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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China













#### N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
50V	1.6Ω @ V <sub>GS</sub> = 10V	500 mA
300	2.5Ω @ V <sub>GS</sub> = 4.5V	200 mA

### **Features and Benefits**

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected to 2KV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

#### **Mechanical Data**

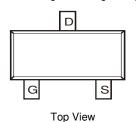
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)

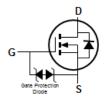




SOT23

Top View





Equivalent Circuit

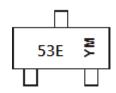
### **Ordering Information** (Note 5)

Part Number	Case	Packaging
DMN53D0LQ-7	SOT23	3,000/Tape & Reel
DMN53D0LQ-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- $5.\ For\ packaging\ details,\ go\ to\ our\ website\ at\ http://www.diodes.com/products/packages.html.$

### **Marking Information**



53E = Product Type Marking Code YM = Date Code Marking Y or = Year (ex: B = 2014) M = Month (ex: 9 = September)

Date Code Key

Year	2014	20	15	2016	2017	20	018	2019	2020	2	021	2022
Code	В	(	C	D	Е		F	G	Н		1	J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	$V_{DSS}$	50	V
Gate-Source Voltage	$V_{GSS}$	±20	V
Drain Current (Note 7)	I <sub>D</sub>	500	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	$P_{D}$	370	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	344	°C/W
Total Power Dissipation (Note 7)	$P_{D}$	540	mW
Thermal Resistance, Junction to Ambient (Note 7)	$R_{ hetaJA}$	236	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

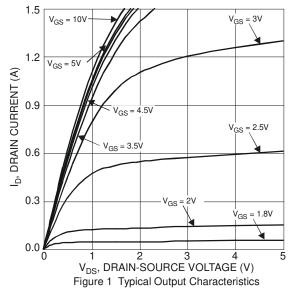
## **Electrical Characteristics** (@ $T_A = +25$ °C, unless otherwise specified.)

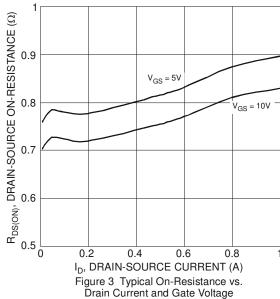
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)					ı	-I	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	50	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1.0	μΑ	$V_{DS} = 50V, V_{GS} = 0V$	
Gate-Body Leakage	I <sub>GSS</sub>	_	_	10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.8	_	1.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
		_	_	1.6		$V_{GS} = 10V, I_D = 500mA$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	_	2.5	Ω	$V_{GS} = 4.5V, I_D = 200mA$	
			_	4.5		$V_{GS} = 2.5V, I_D = 100mA$	
Source-Drain Diode Forward Voltage	V <sub>SD</sub>	_	_	1.4	V	$V_{GS} = 0V, I_{S} = 500mA$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	_	46	_	pF		
Output Capacitance	C <sub>oss</sub>	_	5.3	_	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	4.0	_	рF	1 - 1.000112	
Total Gate Charge	Qg	_	0.6	_	nC	V 45V V 40V	
Gate-Source Charge	Q <sub>gs</sub>	_	0.2	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_{D} = 250 \text{mA}$	
Gate-Drain Charge	$Q_{gd}$	_	0.1	_	nC	- ID = 230IIIA	
Turn-On Delay Time	t <sub>D(on)</sub>	_	2.7	_	ns		
Turn-On Rise Time	t <sub>r</sub>		2.5		ns	$V_{DD} = 30V, V_{GS} = 10V,$ $R_G = 25\Omega, I_D = 200mA$	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	19	_	ns		
Turn-Off Fall Time	t <sub>f</sub>	_	11	_	ns		

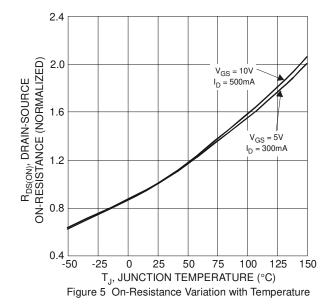
Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout
  Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate
  Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to product testing.

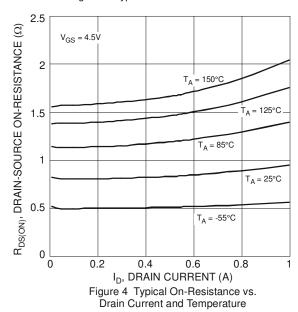








 $V_{DS} = 5V$ 8.0 ID, DRAIN CURRENT (A) 0.6 0.4 85°C 0.2  $T_A = 25^{\circ}C$ -55°C 0 \_ 0.5 1.5 2 2.5 3 3.5  $V_{GS}$ , GATE-SOURCE VOLTAGE (V) Figure 2 Typical Transfer Characteristics



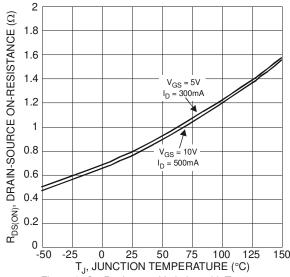


Figure 6 On-Resistance Variation with Temperature



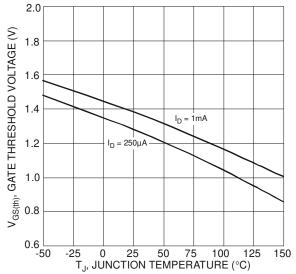
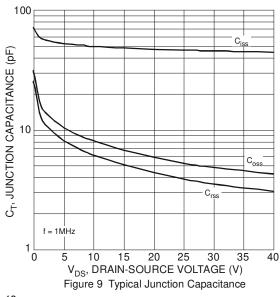
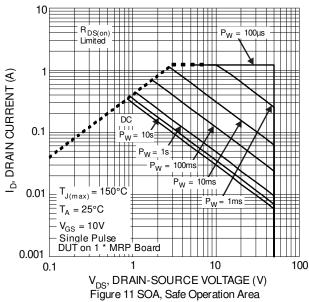
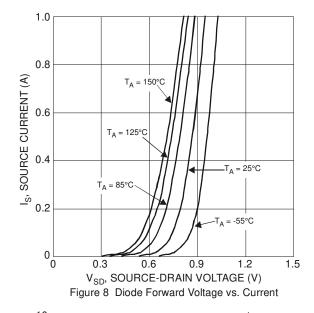
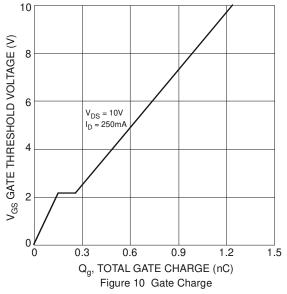


Figure 7 Gate Threshold Variation vs. Ambient Temperature

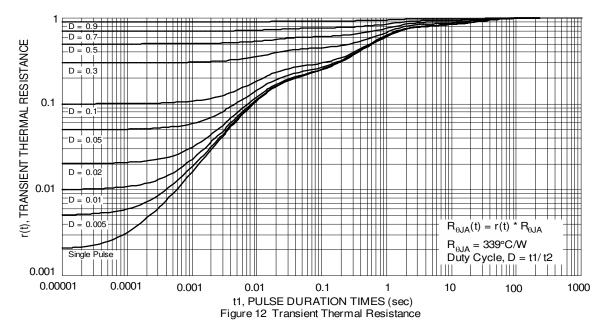








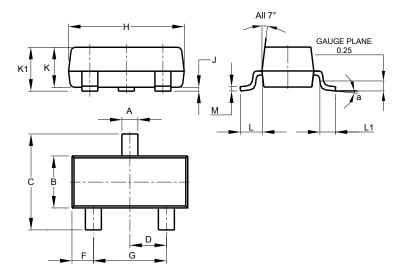






## **Package Outline Dimensions**

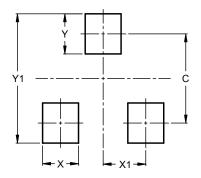
Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
M	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Υ	0.9
Y1	2.9



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